

View Online at <https://aerobasegroup.com/nsn/5961-00-107-6178>

Inclosure Material:

Metal all transistor

Overall Length:

0.240 inches all transistor and 0.260 inches all transistor

Terminal Length:

0.500 inches all transistor

Overall Diameter:

0.350 inches all transistor and 0.370 inches all transistor

Internal Configuration:

Junction contact all transistor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-39 all transistor

Internal Junction Configuration:

Pnp 2nd transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal all transistor

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

40.0 collector to base voltage, dc all transistor

Current Rating Per Characteristic:

0.40 amperes collector current, dc all transistor

Power Rating Per Characteristic:

5.0 watts total device dissipation 2nd transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction all transistor

Terminal Type And Quantity:

3 uninsulated wire lead all transistor

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0